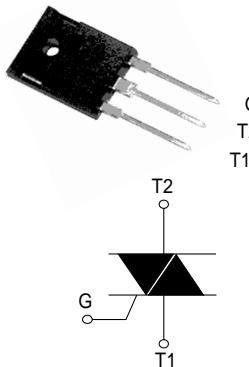
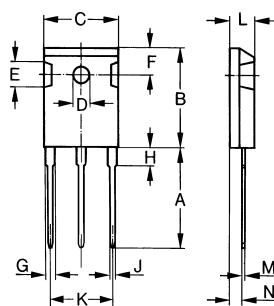


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Discrete Triacs(Non-Isolated/Isolated)



Dimensions TO-247AD



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
$I_T(\text{RMS})$	RMS on-state current (full sine wave)	TO-247AD	$T_c = 80^\circ\text{C}$	41	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	$F = 60 \text{ Hz}$	$t = 16.7 \text{ ms}$	420	A
		$F = 50 \text{ Hz}$	$t = 20 \text{ ms}$	400	
I^2t	I^2t Value for fusing	$t_p = 10 \text{ ms}$			A^2s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r < 100 \text{ ns}$	$F = 120 \text{ Hz}$	$T_j = 125^\circ\text{C}$	50	$\text{A}/\mu\text{s}$
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	$t_p = 10 \text{ ms}$	$T_j = 25^\circ\text{C}$	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20 \mu\text{s}$	$T_j = 125^\circ\text{C}$	8	A
$P_G(\text{AV})$	Average gate power dissipation		$T_j = 125^\circ\text{C}$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range	$-40 \text{ to } +150^\circ\text{C}$ $-40 \text{ to } +125^\circ\text{C}$			$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test Conditions	Quadrant		Value	Unit
$I_{GT}(1)$	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$	I - II - III	MAX.	50	mA
		IV		100	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125^\circ\text{C}$	ALL	MIN.	0.2	V
$I_H(2)$	$I_T = 500 \text{ mA}$		MAX.	80	mA
I_L	$I_G = 1.2 I_{GT}$	I - III-IV	MAX.	70	mA
		II		160	
$dV/dt(2)$	$V_D = 67\% V_{DRM}$ gate open $T_j = 125^\circ\text{C}$	MIN.		500	$\text{V}/\mu\text{s}$
(dI/dt)c (2)	Without snubber $T_j = 125^\circ\text{C}$	MIN.		10	A/ms

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STATIC CHARACTERISTICS

Symbol	Test Conditions			Value	Unit	
V_{TM} (2)	$I_{TM} = 60 \text{ A}$	$t_p = 380 \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.55	V
V_{to} (2)	Threshold voltage		$T_j = 125^\circ\text{C}$	MAX.	0.85	V
R_d (2)	Dynamic resistance		$T_j = 125^\circ\text{C}$	MAX.	10	$\text{m}\Omega$
I_{DRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	MAX.	5	μA	
I_{RRM}		$T_j = 125^\circ\text{C}$		5	mA	

Note 1: minimum IGT is guaranteed at 5% of IGT max.

Note 2: for both polarities of A2 referenced to A1

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	0.6	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Junction to ambient	50	$^\circ\text{C}/\text{W}$

PRODUCT SELECTOR

Part Number	Voltage (xxx)		Sensitivity	Type	Package
	200 V ~ 1000 V				
BTB/BTA41	X	X	50 mA	Standard	TO-247AD

OTHER INFORMATION

Part Number	Marking	Weight	Base quantity	Packing mode
BTB/BTA41	BTB/BTA41	4.5 g	120	Bulk



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Fig. 1: Maximum power dissipation versus RMS on-state current (full cycle).

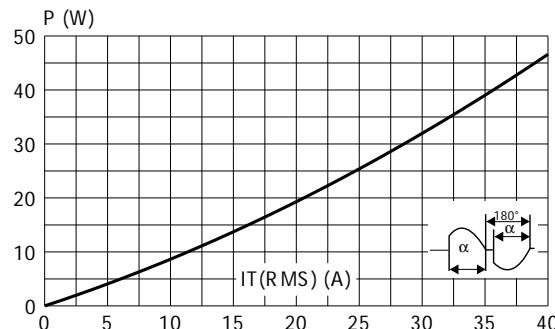


Fig. 3: Relative variation of thermal impedance versus pulse duration.

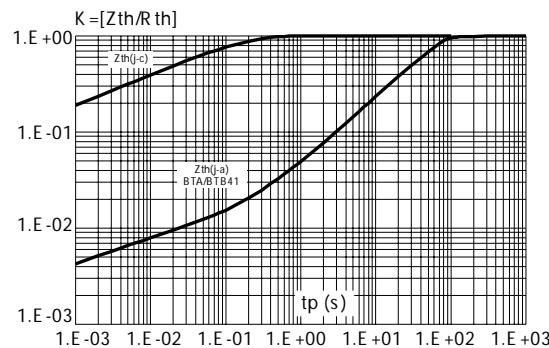


Fig. 5: Surge peak on-state current versus number of cycles.

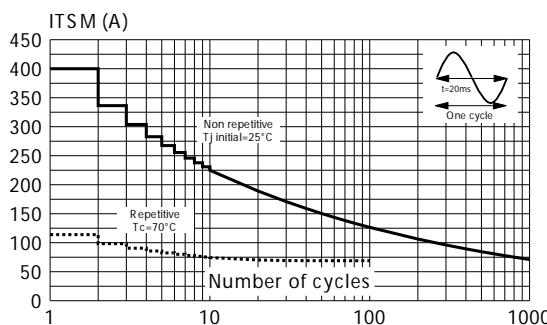


Fig. 2: RMS on-state current versus case temperature (full cycle).

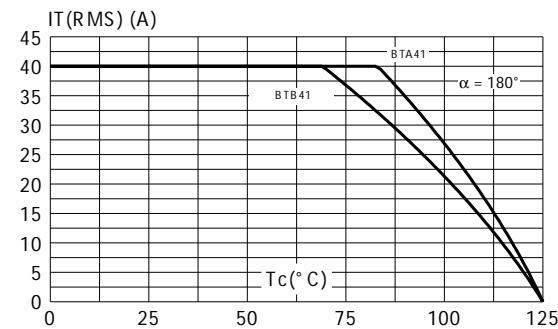


Fig. 4: On-state characteristics (maximum values).

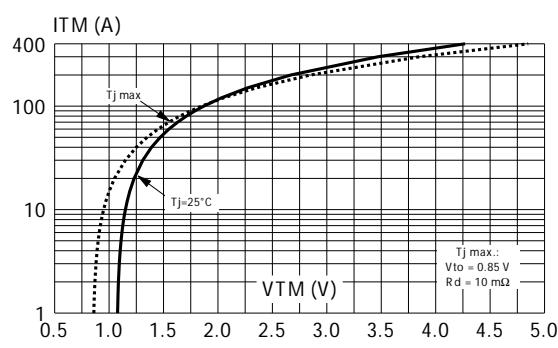
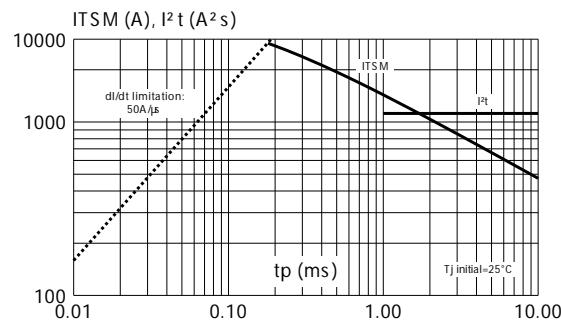


Fig. 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms, and corresponding value of I^2t .



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Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

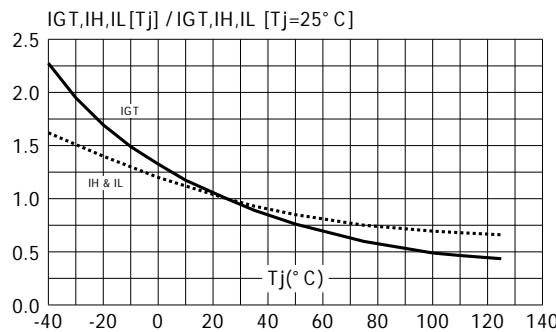


Fig. 8: Relative variation of critical rate of decrease of main current versus $(dV/dt)c$ (typical values).

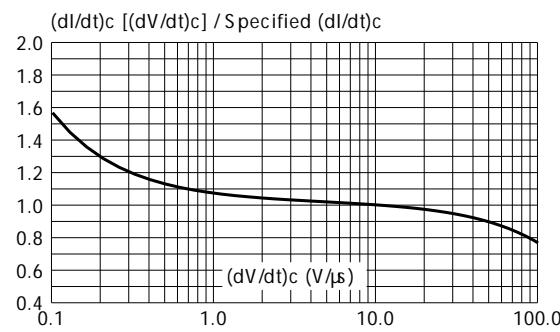


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.

